

Page i

# DIODES, MICROWAVE, GALLIUM ARSENIDE,

# **TUNING VARACTOR,**

# **BASED ON TYPES ML4552 THRU ML4558**

ESCC Detail Specification No. 5512/009

ISSUE 1 October 2002



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Pages 1 to 28

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# **TUNING VARACTOR,**

# BASED ON TYPES ML4552 THRU ML4558

ESA/SCC Detail Specification No. 5512/009

# space components coordination group

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Rev. 'A'

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Rev. Letter	Rev. Date	Reference	CHANGE Item	Approved DCR No.
	Rev. Date	Reference P1. Cover Page P2. DCN P22. Table 3 : Table amended	Item	Approved DCR No. None 221054

	ESA/SCC Detail Specification No. 5512/009		AGE 3 SUE 1
	TABLE OF CONTENTS		Dec
1.	GENERAL		Pac
1.1	Scope		
1.2	Type Variants		
1.3	Maximum Ratings		
1.4	Parameter Derating Information		
1.5	Physical Dimensions		
1.6 1.7	Functional Diagram Handling Precautions		
	-		
2.	APPLICABLE DOCUMENTS		
3.	TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND	<u>D UNITS</u>	
4.	REQUIREMENTS		1
4.1	General		-
4.2	Deviations from Generic Specification		-
4.2.1	Deviations from Special In-process Controls		-
4.2.2	Deviations from Final Production Tests		
4.2.3	Deviations from Burn-in and Electrical Measurements		
4.2.4	Deviations from Qualification Tests		
4.2.5	Deviations from Lot Acceptance Tests Mechanical and Environmental Requirements		•
4.3 4.3.1	Dimension Check		
4.3.1	Weight		
4.3.3	Terminal Strength		
4.3.4	Bond Strength		
4.3.5	Die Shear		
4.4	Materials and Finishes		-
4.4.1	Case		
4.4.2	Lead Materials and Finish		-
4.5	Marking		
4.5.1	General		
4.5.2	Cathode Identification		2
4.5.3	The SCC Component Number		2
4.5.4	Traceability Information		2
4.6	Electrical Measurements		4
4.6.1	Electrical Measurements at Room Temperature		4
4.6.2	Electrical Measurements at High and Low Temperatures		2
4.6.3	Circuits for Electrical Measurements		2
4.7 4.7.1	Burn-in Tests Parameter Drift Values		
4.7.1	Conditions for High Temperature Reverse Bias Burn-in		
4.7.2	Electrical Circuit for High Temperature Reverse Bias Burn-in		4
4.8	Environmental and Endurance Tests		
4.8.1	Electrical Measurements on Completion of Environmental Tes	its	2
4.8.2	Electrical Measurements at Intermediate Points and on Compl		
4.8.3	Conditions for Operating Life Tests		
4.8.4	Electrical Circuits for Operating Life Tests		2
4.9	Total Dose Irradiation Testing		2
4.9.1	Application		
4.9.2	Bias Conditions		2
4.9.3	Electrical Measurements		
4.10	Special Testing		2

<b>See</b>	ESA/SCC Detail Specification No. 5512/009		PAGE ISSUE	4 1
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#### **TABLES**

<u>Page</u>

1(a)	Type Variants	6
1(b)	Maximum Ratings	9
2	Electrical Measurements at Room Temperature - D.C. Parameters	21
	Electrical Measurements at Room Temperature - A.C. Parameters	21
3	Electrical Measurements at High and Low Temperatures	22
4	Parameter Drift Values	22
5(a)	Conditions for High Temperature Reverse Bias Burn-in	24
5(b)	Conditions for Operating Life Tests	24
6	Electrical Measurements at Intermediate Points and on Completion of Endurance Testing	26
7	Electrical Measurements During and on Completion of Irradiation Testing	27

### **FIGURES**

1	Parameter Derating Information	9
2	Physical Dimensions	10
3	Functional Diagram	16
4	Circuits for Electrical Measurements	23
5	Electrical Circuit for High Temperature Reverse Bias Burn-in and Operating Life Tests	24
6	Bias Conditions for Irradiation Testing	26

# APPENDICES (Applicable to specific Manufacturers only) 'A' Agreed Deviations for M/A-Com Ltd. (G.B.)

28



#### 1. <u>GENERAL</u>

#### 1.1 <u>SCOPE</u>

This specification details the ratings, physical and electrical characteristics, test and inspection data for a Diode, Microwave, Gallium Arsenide, Tuning Varactor, based on Types ML4552 thru ML4558. It shall be read in conjunction with ESA/SCC Generic Specification No. 5010, the requirements of which are supplemented herein.

#### 1.2 <u>TYPE VARIANTS</u>

Variants of the basic diodes specified herein, which are also covered by this specification are given in Table 1(a).

#### 1.3 MAXIMUM RATINGS

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the diodes specified herein, are as scheduled in Table 1(b).

#### 1.4 PARAMETER DERATING INFORMATION

The derating information applicable to the diodes specified herein is shown in Figure 1.

#### 1.5 PHYSICAL DIMENSIONS

The physical dimensions of the diodes specified herein are shown in Figure 2.

#### 1.6 FUNCTIONAL DIAGRAM

The functional diagram, showing lead identification, of the diodes specified herein, is shown in Figure 3.

#### 1.7 HANDLING PRECAUTIONS

These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

These components are Categorised as Class 2 with a Minimum Critical Path Failure Voltage of 3000V.

#### 2. APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 5010 for Discrete Microwave Semiconductor Components.
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.

#### 3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply.



PAGE 6

ISSUE 1

# TABLE 1(a) - TYPE VARIANTS

(1) VARIANT	(2) BASED ON TYPE	(3) FIGURE	(4) TOTAL CAPACITANCE C <sub>T</sub> (pF)		(5) QUALITY FACTOR (Q) (MINIMUM)	(6) BODY-LID AND LEAD MATERIAL AND FINISH
			MIN	МАХ	(,	
01	ML4552 - 30	2(a)	0.40	0.74	5000	A7-D2
02	ML4552 - 31	2(b)	0.40	0.74	5000	A7-D2
03	ML4552 - 33	2(c)	0.40	0.74	5000	A7
04	ML4552 - 36	2(d)	0.40	0.74	5000	A7-D2
05	ML4552 - 94	2(e)	0.40	0.74	5000	A7-D2
06	ML4552 - 95	2(f)	0.40	0.74	5000	A7-D2
07	ML4552 - 96	2(g)	0.40	0.74	5000	A7-D2
08	ML4552 - 97	2(h)	0.40	0.74	5000	A7-D2
09	ML4552 - 103	2(i)	0.40	0.74	5000	A7-D2
10	ML4552 - 118	2(j)	0.40	0.74	5000	A7
11	ML4552 - 120	2(k)	0.40	0.74	5000	D2
12	ML4552 - 186	2(l)	0.40	0.74	5000	D2
13	ML4552 - 276	2(m)	0.40	0.74	5000	D2
14	ML4553 - 30	2(a)	0.75	0.99	5000	A7-D2
15	ML4553 - 31	2(b)	0.75	0.99	5000	A7-D2
16	ML4553 - 33	2(c)	0.75	0.99	5000	A7
17	ML4553 - 36	2(d)	0.75	0.99	5000	A7-D2
18	ML4553 - 94	2(e)	0.75	0.99	5000	A7-D2
19	ML4553 - 95	2(f)	0.75	0.99	5000	A7-D2
20	ML4553 - 96	2(g)	0.75	0.99	5000	A7-D2
21	ML4553 - 97	2(h)	0.75	0.99	5000	A7-D2
22	ML4553 - 103	2(i)	0.75	0.99	5000	A7-D2
23	ML4553 - 118	2(j)	0.75	0.99	5000	A7
24	ML4553 - 120	2(k)	0.75	0.99	5000	D2
25	ML4553 - 186	2(I)	0.75	0.99	5000	D2
26	ML4553 - 276	2(m)	0.75	0.99	5000	D2
27	ML4554 - 30	2(a)	1.00	1.49	5000	A7-D2
28	ML4554 - 31	2(b)	1.00	1.49	5000	A7-D2
29	ML4554 - 33	2(c)	1.00	1.49	5000	A7
30	ML4554 - 36	2(d)	1.00	1.49	5000	A7-D2
31	ML4554 - 94	2(e)	1.00	1.49	5000	A7-D2
32	ML4554 - 95	2(f)	1.00	1.49	5000	A7-D2
33	ML4554 - 96	2(g)	1.00	1.49	5000	A7-D2
34	ML4554 - 97	2(h)	1.00	1.49	5000	A7-D2
35	ML4554 - 103	2(i)	1.00	1.49	5000	A7-D2
36	ML4554 - 118	2(j)	1.00	1.49	5000	A7



PAGE 7

ISSUE 1

## TABLE 1(a) - TYPE VARIANTS (CONT'D)

(1) VARIANT	(2) BASED ON TYPE	(3) FIGURE	(4) TOTAL CAPACITANCE C <sub>T</sub> (pF)		(5) QUALITY FACTOR (Q) (MINIMUM)	(6) BODY-LID AND LEAD MATERIAL AND FINISH
			MIN	МАХ	(	
37	ML4554 - 120	2(k)	1.00	1.49	5000	D2
38	ML4554 - 186	2(l)	1.00	1.49	5000	D2
39	ML4554 - 276	2(m)	1.00	1.49	5000	D2
40	ML4555 - 30	2(a)	1.50	1.99	5000	A7-D2
41	ML4555 - 31	2(b)	1.50	1.99	5000	A7-D2
42	ML4555 - 33	2(c)	1.50	1.99	5000	A7
43	ML4555 - 36	2(d)	1.50	1.99	5000	A7-D2
44	ML4555 - 94	2(e)	1.50	1.99	5000	A7-D2
45	ML4555 - 95	2(f)	1.50	1.99	5000	A7-D2
46	ML4555 - 96	2(g)	1.50	1.99	5000	A7-D2
47	ML4555 - 97	2(h)	1.50	1.99	5000	A7-D2
48	ML4555 - 103	2(i)	1.50	1.99	5000	A7-D2
49	ML4555 - 118	2(j)	1.50	1.99	5000	A7
50	ML4555 - 120	2(k)	1.50	1.99	5000	D2
51	ML4555 - 186	2(I)	1.50	1.99	5000	D2
52	ML4555 - 276	2(m)	1.50	1.99	5000	D2
53	ML4556 - 30	2(a)	2.00	2.49	4000	A7-D2
54	ML4556 - 31	2(b)	2.00	2.49	4000	A7-D2
55	ML4556 - 33	2(c)	2.00	2.49	4000	A7
56	ML4556 - 36	2(d)	2.00	2.49	4000	A7-D2
57	ML4556 - 94	2(e)	2.00	2.49	4000	A7-D2
58	ML4556 - 95	2(f)	2.00	2.49	4000	A7-D2
59	ML4556 - 96	2(g)	2.00	2.49	4000	A7-D2
60	ML4556 - 97	2(h)	2.00	2.49	4000	A7-D2
61	ML4556 - 103	2(i)	2.00	2.49	4000	A7-D2
62	ML4556 - 118	2(j)	2.00	2.49	4000	A7
63	ML4556 - 120	2(k)	2.00	2.49	4000	D2
64	ML4556 - 186	2(I)	2.00	2.49	4000	D2
65	ML4556 - 276	2(m)	2.00	2.49	4000	D2
66	ML4557 - 30	2(a)	2.50	2.99	4000	A7-D2
67	ML4557 - 31	2(b)	2.50	2.99	4000	A7-D2
68	ML4557 - 33	2(c)	2.50	2.99	4000	A7
69	ML4557 - 36	2(d)	2.50	2.99	4000	A7-D2
70 ·	ML4557 - 94	2(e)	2.50	2.99	4000	A7-D2
. 71	ML4557 - 95	2(f)	2.50	2.99	4000	A7-D2
72	ML4557 - 96	2(g)	2.50	2.99	4000	A7-D2

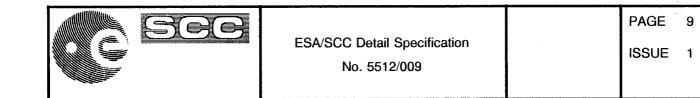


PAGE 8

ISSUE 1

# TABLE 1(a) - TYPE VARIANTS (CONT'D)

(1) VARIANT	(2) BASED ON TYPE	(3) FIGURE	(4) TOTAL CAPACITANCE C <sub>T</sub> (pF)		(5) QUALITY FACTOR (Q) (MINIMUM)	(6) BODY-LID AND LEAD MATERIAL AND FINISH
			MIN	MAX		
73	ML4557 - 97	2(h)	2.50	2.99	4000	A7-D2
74	ML4557 - 103	2(i)	2.50	2.99	4000	A7-D2
75	ML4557 - 118	2(j)	2.50	2.99	4000	A7
76	ML4557 - 120	2(k)	2.50	2.99	4000	D2
77	ML4557 - 186	2(l)	2.50	2.99	4000	D2
78	ML4557 - 276	2(m)	2.50	2.99	4000	D2
79	ML4558 - 30	2(a)	3.00	3.99	4000	A7-D2
80	ML4558 - 31	2(b)	3.00	3.99	4000	A7-D2
81	ML4558 - 33	2(c)	3.00	3.99	4000	A7
82	ML4558 - 36	2(d)	3.00	3.99	4000	A7-D2
83	ML4558 - 94	2(e)	3.00	3.99	4000	A7-D2
84	ML4558 - 95	2(f)	3.00	3.99	4000	A7-D2
85	ML4558 - 96	2(g)	3.00	3.99	4000	A7-D2
86	ML4558 - 97	2(h)	3.00	3.99	4000	A7-D2
87	ML4558 - 103	2(i)	3.00	3.99	4000	A7-D2
88	ML4558 - 118	2(j)	3.00	3.99	4000	A7
89	ML4558 - 120	2(k)	3.00	3.99	4000	D2
90	ML4558 - 186	2(l)	3.00	3.99	4000	D2
91	ML4558 - 276	2(m)	3.00	3.99	4000	D2



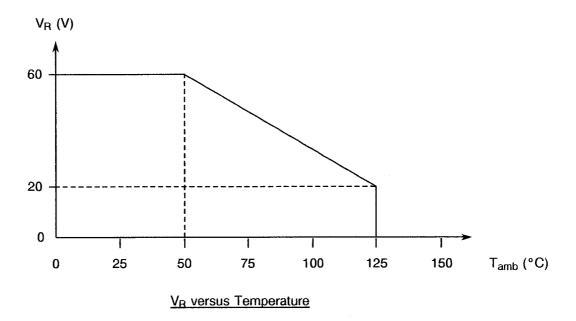
#### TABLE 1(b) - MAXIMUM RATINGS

No.	CHARACTERISTIC	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	D.C. Reverse Voltage	V <sub>R</sub>	- 60	V	Note 1
2	Operating Temperature Range	Т <sub>ор</sub>	- 40 to + 125	°C	T <sub>amb</sub>
3	Storage Temperature Range	T <sub>stg</sub>	-55 to +125	°C	
4	Soldering Temperature	T <sub>sol</sub>	+ 230	°C	Note 2

#### **NOTES**

- 1. Measured at  $I_R = 10\mu A$  and  $T_{amb} = +50^{\circ}C$ . For derating at  $T_{amb} > +50^{\circ}C$ , see Figure 1.
- 2. Duration 5 seconds maximum (at a distance of not less than 1.5mm from the body for Variants 12, 13, 25, 26, 38, 39, 51, 52, 64, 65, 77, 78, 90 and 91) and the same termination shall not be resoldered until 3 minutes have elapsed.

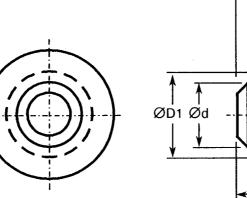
#### FIGURE 1 - PARAMETER DERATING INFORMATION

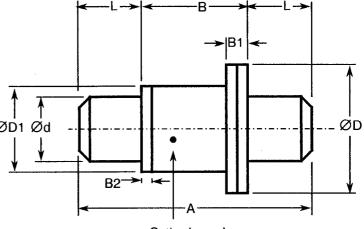




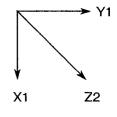
#### FIGURE 2 - PHYSICAL DIMENSIONS

# FIGURE 2(a) - VARIANTS 01, 14, 27, 40, 53, 66, 79



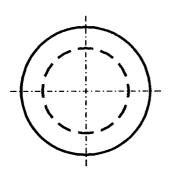




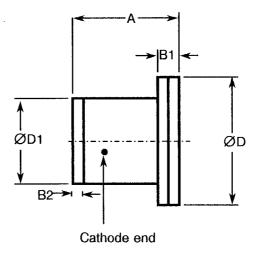


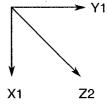
	ī	
SYMBOL	MILLIM	ETRES
STIVIDUL	MIN	MAX
А	5.20	5.72
В	2.16	2.46
B1	0.41	0.61
B2	0.15	0.25
Ød	1.52	1.63
ØD	3.00	3.23
ØD1	1.95	2.11
L	1.52	1.63

#### FIGURE 2(b) - VARIANTS 02, 15, 28, 41, 54, 67, 80



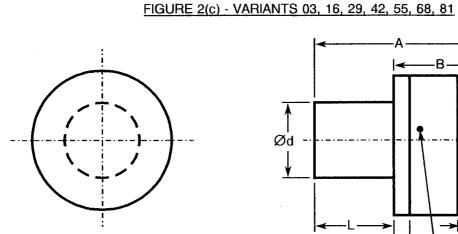
SYMBOL	MILLIM	ETRES
STMDUL	MIN	MAX
А	2.16	2.46
B1	0.41	0.61
B2	0.15	0.25
ØD	3.00	3.23
ØD1	1.95	2.11

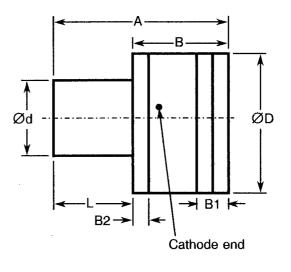


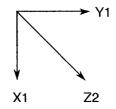




#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

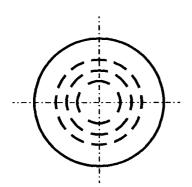




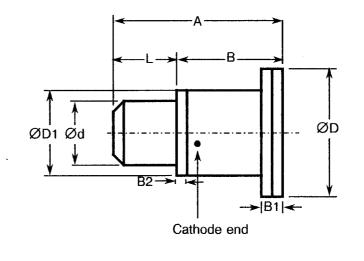


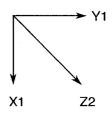
SYMBOL	MILLIMETRES			
STMBUL	MIN	MAX		
А	1.41	1.85		
В	0.69	1.02		
B1	0.30	0.50		
B2	0.05	0.13		
Ød	0.61	0.66		
ØD	1.22	1.32		
L	0.74	0.79		

#### FIGURE 2(d) - VARIANTS 04, 17, 30, 43, 56, 69, 82



SYMBOL	MILLIMETRES		
STMDUL	MIN	MAX	
A	3.60	4.18	
В	2.16	2.46	
B1	0.41	0.61	
B2	0.15	0.25	
Ød	1.52	1.63	
ØD	3.00	3.23	
ØD1	1.95	2.11	
L	1.52	1.63	

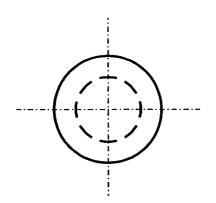


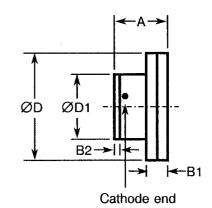




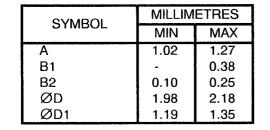
#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

#### FIGURE 2(e) - VARIANTS 05, 18, 31, 44, 57, 70, 83

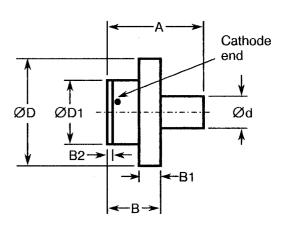




X1

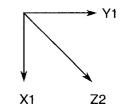


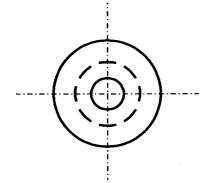
#### FIGURE 2(f) - VARIANTS 06, 19, 32, 45, 58, 71, 84



≻ Y1

Ζ2



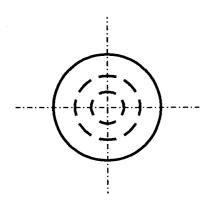


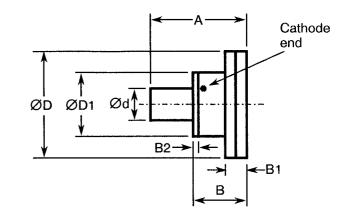
SYMBOL	MILLIMETRES		
STNIDOL	MIN	MAX	
А	1.78	2.03	
В	1.02	1.27	
B1	-	0.38	
B2	0.10	0.25	
Ød	0.61	0.66	
ØD	1.98	2.18	
ØD1	1.19	1.35	



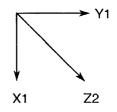
#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

#### FIGURE 2(g) - VARIANTS 07, 20, 33, 46, 59, 72, 85

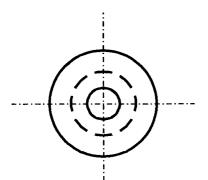




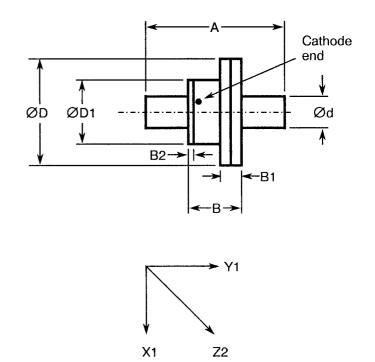
SYMBOL	MILLIN	MILLIMETRES		
STNDUL	MIN	MAX		
А	1.78	2.03		
В	1.02	1.27		
B1	-	0.38		
B2	0.10	0.25		
Ød	0.61	0.66		
ØD	1.98	2.18		
ØD1	1.19	1.35		



#### FIGURE 2(h) - VARIANTS 08, 21, 34, 47, 60, 73, 86



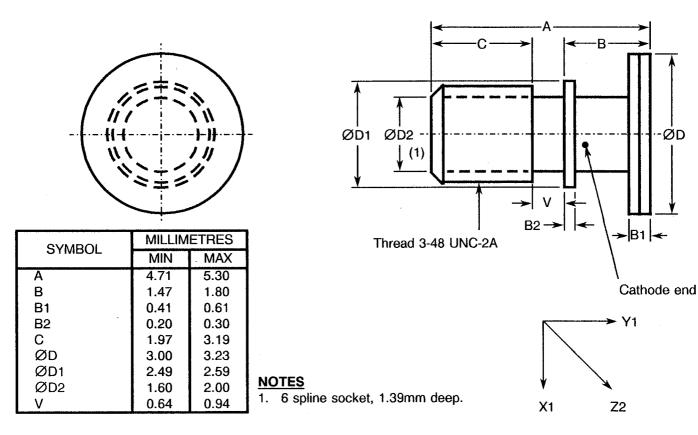
SYMBOL	MILLIM	MILLIMETRES		
STMBOL	MIN	MAX		
А	2.54	2.79		
В	1.02	1.27		
B1	-	0.38		
B2	0.10	0.25		
Ød	0.61	0.66		
ØD	1.98	2.18		
ØD1	1.19	1.35		



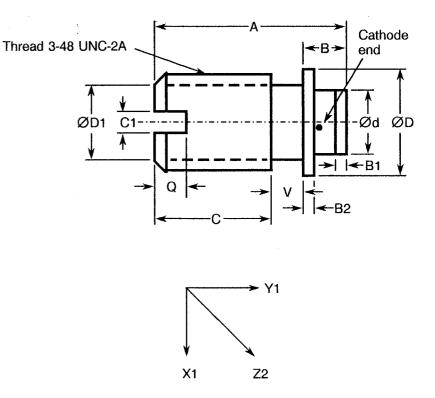


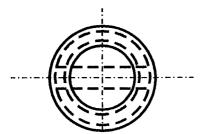
#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

FIGURE 2(i) - VARIANTS 09, 22, 35, 48, 61, 74, 87

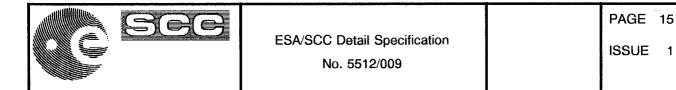


#### FIGURE 2(j) - VARIANTS 10, 23, 36, 49, 62, 75, 88



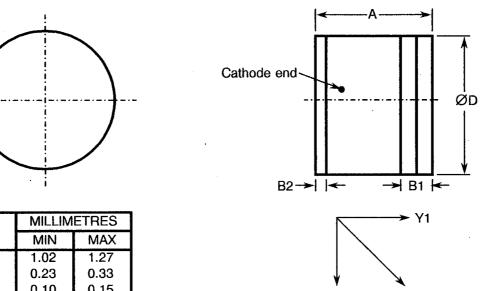


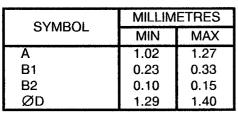
	•		
SYMBOL	MILLIMETRES		
STIVIDUL	MIN	MAX	
A	4.19	4.70	
B	0.77	1.04	
B1	0.20	0.30	
B2	0.22	0.28	
С	2.21	3.29	
C1	0.38	0.64	
Ød	1.22	1.32	
ØD	2.49	2.59	
ØD1	1.60	2.00	
Q	0.64	1.14	
V	0.64	0.94	



# FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

### FIGURE 2(k) - VARIANTS 11, 24, 37, 50, 63, 76, 89





В

d

Е

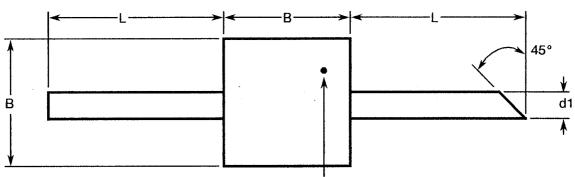
L

S

0.10

-

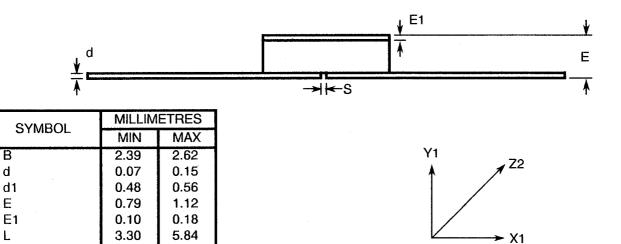
FIGURE 2(I) - VARIANTS 12, 25, 38, 51, 64, 77, 90

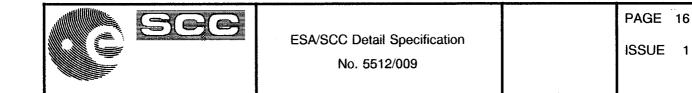




Z2

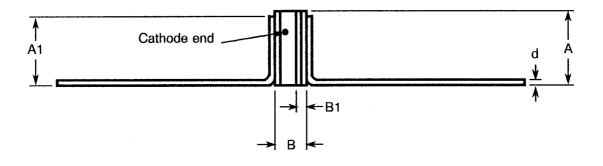
X1

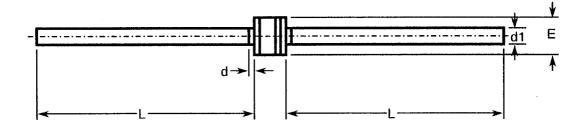




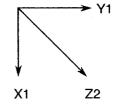
#### FIGURE 2 - PHYSICAL DIMENSIONS (CONTINUED)

FIGURE 2(m) - VARIANTS 13, 26, 39, 52, 65, 78, 91

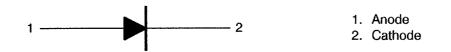




SYMBOL	MILLIM	MILLIMETRES		
STMDUL	MIN	MAX		
A	1.35	2.54		
A1	- ·	2.46		
В	1.02	1.27		
B1	-	0.38		
d	0.07	0.15		
d1	0.38	0.64		
E	1.29	1.40		
L	6.10	12.40		



#### FIGURE 3 - FUNCTIONAL DIAGRAM



#### **NOTES**

1. The cathode end shall be marked with a black dot or band. The marking will not be on the cathode connection but adjacent to it.



1

ISSUE

#### 4. **REQUIREMENTS**

#### 4.1 <u>GENERAL</u>

The complete requirements for procurement of the diodes specified herein shall be as stated in this specification and ESA/SCC Generic Specification No. 5010 for Discrete Microwave Semiconductor Components. Deviations from the Generic Specification applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

#### 4.2 DEVIATIONS FROM GENERIC SPECIFICATION

#### 4.2.1 Deviations from Special In-process Controls

- (a) Para. 5.2.2, Total Dose Irradiation Testing: Shall be performed during qualification and extension of qualification.
- (b) Para. 5.2.2, Total Dose Irradiation Testing: Shall be performed during procurement on a lot acceptance basis at the total dose irradiation level specified in the purchase order.
- (c) Para. 5.3, Wafer Lot Acceptance: Shall be performed as an S.E.M. Inspection only.
- (d) Quality Factor Measurement (Q): 3 randomly chosen samples shall be encapsulated in the type of package shown in Figure 2(a) of this specification. After encapsulation, Quality Factor measurements shall be performed using the method shown in Figure 4 of this specification with  $V_{\rm B} = -4.0V$ . The limits specified in Table 1(a) of this specification shall be met.

#### 4.2.2 Deviations from Final Production Tests (Chart II)

(a) Para. 9.14, Vibration, Variable Frequency: Shall not be performed.

#### 4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)

(a) Para. 7.1.1(a), High Temperature Reverse Bias Burn-in: Shall be performed at 33% of rated V<sub>R</sub>.

# 4.2.4 <u>Deviations from Qualification Tests (Chart IV)</u>(a) Para. 9.23, Special Testing: Shall not be performed.

4.2.5 Deviations from Lot Acceptance Tests (Chart V)

(a) Para. 9.23, Special Testing: Shall not be performed.

#### 4.3 MECHANICAL AND ENVIRONMENTAL REQUIREMENTS

#### 4.3.1 Dimension Check

The dimensions of the diodes specified herein shall be checked. They shall conform to those shown in Figure 2.



#### 4.3.2 Weight

The maximum weight of the diodes specified herein shall be:

Variant No.	Weight (g)
01, 14, 27, 40, 53, 66, 79	0.12
02, 15, 28, 41, 54, 67, 80	0.06
03, 16, 29, 42, 55, 68, 81	0.01
04, 17, 30, 43, 56, 69, 82	0.10
05, 18, 31, 44, 57, 70, 83	0.013
06, 07, 19, 20, 32, 33, 45, 46, 58, 59, 71, 72, 84, 85	0.015

Variant No.	Weight (g)
08, 21, 34, 47, 60, 73, 86	0.022
09, 10, 22, 23, 35, 36, 48, 49, 61, 62, 74, 75, 87, 88	0.14
11, 24, 37, 50, 63, 76, 89	0.014
12, 25, 38, 51, 64, 77, 90	0.06
13, 26, 39, 52, 65, 78, 91	0.025

#### 4.3.3 Terminal Strength

The requirements for terminal strength testing are specified in Section 9 of ESA/SCC Generic Specification No. 5010. The test conditions shall be as follows:-

#### (a) Condition: 'A' (Tension)

Variants 12, 25, 38, 51, 64, 77 and 90:

- Force: 5.1N.
- Duration: 5 seconds.

Variants 13, 26, 39, 52, 65, 78 and 91:

- Force: 1.22N.
- Duration: 5 seconds.

#### (b) Condition: 'D2' (Stud Torque)

Variants 09, 22, 35, 48, 61, 74 and 87:

- Torque: 56mNm.
- Duration: 5 seconds.

Variants 10, 23, 36, 49, 62, 75 and 88:

- Torque: 42mNm.
- Duration: 5 seconds.

#### (c) Condition: Compression

Variants 01, 02, 04, 09, 14, 15, 17, 21, 27, 28, 30, 35, 40, 41, 43, 48, 53, 54, 56, 61, 66, 67, 69, 74, 79, 80, 82 and 87:

- Force: 50N.
- Duration: 5 seconds.

Variants 03, 05, 06, 07, 08, 10, 11, 16, 18, 19, 20, 21, 23, 24, 29, 31, 32, 33, 34, 36, 37, 42, 44, 45, 46, 47, 49, 50, 55, 57, 58, 59, 60, 62, 63, 68, 70, 71, 72, 73, 75, 76, 81, 83, 84, 85, 86, 88 and 89:

- Force: 10N.
- Duration: 5 seconds.

The compression test shall be performed by applying the specified force to the end-cap by means of a suitable weight applied for the specified time. On completion of the test, a visual examination shall be performed to check for damage to the end-cap or the ceramic body.



#### 4.3.4 Bond Strength

The requirements for bond strength are as specified in Section 9 of ESA/SCC Generic Specification No. 5010. The test conditions shall be as follows:

- (a) Condition : 'A'.
- (b) Separating Force : 0.02N minimum.

#### 4.3.5 Die Shear

The requirements for die shear are as specified in Section 9 of ESA/SCC Generic Specification No. 5010. The test conditions shall be as follows:

(a) Force : 0.45N minimum.

#### 4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the diodes specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material shall not guarantee acceptance of the finished product.

#### 4.4.1 <u>Case</u>

The case shall be hermetically sealed and have a ceramic body. The lid shall be brazed, welded or preform soldered.

#### 4.4.2 Lead Materials and Finish

- (a) For Variants 01, 02, 04, 05, 06, 07, 08, 09, 14, 15, 17, 18, 19, 20, 21, 22, 27, 28, 30, 31, 32, 33, 34, 35, 40, 41, 43, 44, 45, 46, 47, 48, 53, 54, 56, 57, 58, 59, 60, 61, 66, 67, 69, 70, 71, 72, 73, 74, 79, 80, 82, 83, 84, 85, 86 and 87, the body material shall be Type 'A' with Type '7' finish and the lid material shall be Type 'D' with Type '2' finish, in accordance with the requirements of ESA/SCC Basic Specification No. 23500.
- (b) For Variants 03, 10, 16, 23, 29, 36, 42, 49, 55, 62, 68, 75, 81 and 88, the lead material shall be Type 'A' with Type '7' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500.
- (c) For Variants 11, 12, 13, 24, 25, 26, 37, 38, 39, 50, 51, 52, 63, 64, 65, 76, 77, 78, 89, 90 and 91, the lead material shall be Type 'D' with Type '2' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500.

#### 4.5 MARKING

4.5.1 <u>General</u>

The marking of components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700 and the following paragraphs. When the component is too small to accommodate all of the marking specified, as much as space permits shall be marked and the marking information, in full, shall accompany the component in its primary package.

The information to be marked and the order of precedence, shall be as follows:-

- (a) Cathode Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.



#### 4.5.2 <u>Cathode Identification</u>

Cathode identification shall be as shown in Figures 2 and 3 of this specification.

#### 4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:

	551200901BF
Detail Specification Number	
Type Variant (see Table 1(a))	
Testing Level (B or C, as applicable)	]
Total Dose Irradiation Level (if applicable)	

The Total Dose Irradiation Level designation shall be added for those devices for which a sample has been successfully tested to the level in question. For these devices, a code letter shall be added in accordance with the requirements of ESA/SCC Basic Specification No. 22900.

#### 4.5.4 <u>Traceability Information</u>

Each component shall be marked in respect of traceability information as defined in ESA/SCC Basic Specification No. 21700.

#### 4.6 ELECTRICAL MEASUREMENTS

4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise specified, the measurements shall be performed at  $T_{amb}$  = +22 ± 3 °C.

#### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. Unless otherwise specified, the measurements shall be performed at  $T_{amb} = +125(+0-3)$  °C.

#### 4.6.3 Circuits for Electrical Measurements

A circuit for use in performing the quality factor measurement is shown in Figure 4.

#### 4.7 BURN-IN TESTS

Burn-in shall be Category 1 of Chart III(a).

#### 4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C. The parameter drift values ( $\Delta$ ) applicable to the scheduled parameters shall not be exceeded. In addition to these drift value requirements for a given parameter, the appropriate limit value specified in Table 2 shall not be exceeded.

#### 4.7.2 Conditions for High Temperature Reverse Bias Burn-in

The requirements for the high temperature reverse bias burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5010. The conditions for high temperature reverse bias burn-in shall be as specified in Table 5(a) of this specification.

#### 4.7.3 Electrical Circuit for High Temperature Reverse Bias Burn-in

The circuit for use in performing the H.T.R.B burn-in test is shown in Figure 5 of this specification.



#### TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - D.C. PARAMETERS

No. CHARACTERIS		MIL-STD-750	TEST CONDITIONS	LIMITS		UNIT	
		TEST METHOD		MIN.	MAX.		
1	Reverse Current 1	I <sub>R1</sub>	4016	V <sub>R</sub> = -60V	-	10	μΑ
2	Reverse Current 2	I <sub>R2</sub>	4016	V <sub>R</sub> = -40V	-	100	nA
3	Forward Voltage	V <sub>F</sub>	4011	l <sub>F</sub> = 10μA	-	1.1	V

#### TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - A.C. PARAMETERS

No	No. CHARACTERISTICS		SYMBOL	MIL-STD-750	TEST	LIM	ITS	UNIT
110.	CHARGERISTICS	STWDUE	TEST METHOD	CONDITIONS	MIN.	MAX.		
4	Total Capacitance	CT	4001	V <sub>R</sub> = -4.0V f = 1.0MHz	Not	e 1	pF	
5	Total Capacitance Ratio	-	4001	$V_{R} = 0V$ $V_{R} = -60V$ $f = 1.0MHz$ Note 2 Variants 01 to 13 Variants 14 to 26 Variants 27 to 39 Variants 40 to 52 Variants 53 to 65 Variants 66 to 78 Variants 79 to 91	2.3 2.8 3.1 3.6 4.5 4.7 4.9	- - - -		

#### **NOTES**

1. See Column 4 of Table 1(a).

2. Ratio =  $\frac{C_T \text{ at } V_R = 0V}{C_T \text{ at } V_R = -60V}$ 



Rev. 'A'

# TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	ONT
6	Reverse Current 3	I <sub>R3</sub>	4016	V <sub>R</sub> = -20V	-	10	μΑ

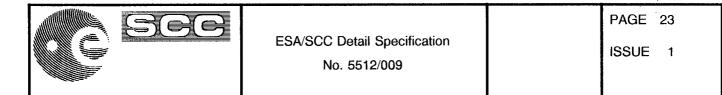
#### TABLE 4 - PARAMETER DRIFT VALUES

No.	CHARACTERISTICS	SYMBOL	SPEC.AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
2	Reverse Current 2	I <sub>R2</sub>	As per Table 2	As per Table 2	± 10 (1) or (2) ± 100 (1)	nA %
3	Forward Voltage	V <sub>F</sub>	As per Table 2	As per Table 2	± 100 (1)	mV

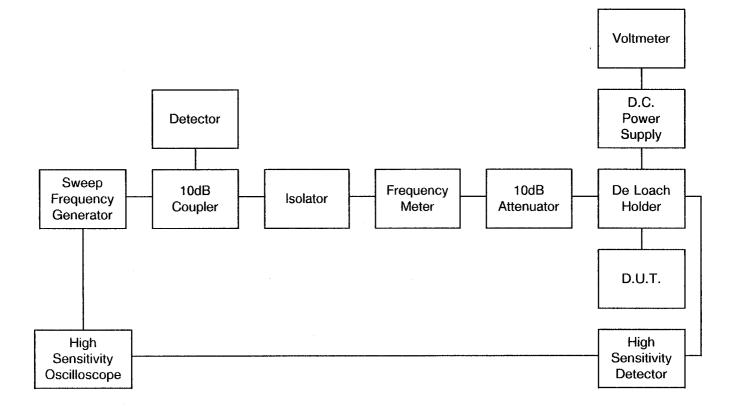
#### **NOTES**

1.  $\Delta 1 = \Delta 2$ .

2. Whichever is the greater, referred to the initial measurement.



#### FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS





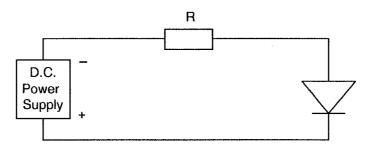
#### TABLE 5(a) - CONDITIONS FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN

No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature	T <sub>amb</sub>	+ 125( + 0 - 3)	°C
2	Reverse Voltage	V <sub>R</sub>	-20	V

#### TABLE 5(b) - CONDITIONS FOR OPERATING LIFE TESTS

No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Ambient Temperature 1	T <sub>amb1</sub>	+ 115( + 0 - 3)	°C
2	Reverse Voltage 1	V <sub>R1</sub>	- 20	V
3	Ambient Temperature 2	T <sub>amb2</sub>	+ 125( + 0 - 3)	°C
4	Reverse Voltage 2	V <sub>R2</sub>	- 20	V

#### FIGURE 5 - ELECTRICAL CIRCUIT FOR HIGH TEMPERATURE REVERSE BIAS BURN-IN AND OPERATING LIFE TESTS





#### 4.8 <u>ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC</u> <u>SPECIFICATION NO. 5010)</u>

#### 4.8.1 Electrical Measurements on Completion of Environmental Tests

The parameters to be measured on completion of environmental tests are scheduled in Table 2. Unless otherwise stated, the measurements shall be performed at  $T_{amb}$  = +22 ± 3 °C.

#### 4.8.2 Electrical Measurements at Intermediate Points and on Completion of Endurance Tests

The parameters to be measured at intermediate points and on completion of endurance tests are scheduled in Table 6. Unless otherwise stated, the measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.8.3 Conditions for Operating Life Tests (Part of Endurance Testing)

The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 5010. The conditions for operating life testing are specified in Table 5(b) of this specification.

4.8.4 <u>Electrical Circuits for Operating Life Tests</u>

The circuit to be used for performance of the operating life test shall be the same as shown in Figure 5 for High Temperature Reverse Bias Burn-in.

#### 4.9 TOTAL DOSE IRRADIATION TESTING

4.9.1 Application

If specified in Para. 4.2.1 of this specification, total dose irradiation testing shall be performed in accordance with the requirements of ESA/SCC Basic Specification No. 22900.

#### 4.9.2 Bias Conditions

Continuous bias shall be applied during irradiation testing as shown in Figure 6 of this specification.

#### 4.9.3 Electrical Measurements

The parameters to be measured prior to irradiation exposure are scheduled in Table 2 of this specification. Only devices which meet the requirements of Table 2 shall be included in the test sample.

The parameters to be measured during and on completion of irradiation testing are scheduled in Table 7 of this specification.

#### 4.10 SPECIAL TESTING

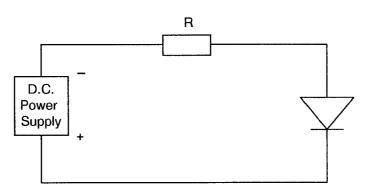
Not applicable.



#### TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS AND ON COMPLETION OF ENDURANCE TESTING

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS MIN. MAX.	UNIT
1	Reverse Current 1	I <sub>R1</sub>	As per Table 2	As Per Table 2	As Per Table 2	μΑ
2	Reverse Current 2	I <sub>R2</sub>	As per Table 2	As Per Table 2	As Per Table 2	nA
3	Forward Voltage	V <sub>F</sub>	As per Table 2	As per Table 2	As per Table 2	V
4	Total Capacitance	CT	As per Table 2	As per Table 2	As per Table 2	pF

#### FIGURE 6 - BIAS CONDITIONS FOR IRRADIATION TESTING



#### **NOTES**

1. A reverse bias of  $V_{\rm R}$  = -20V, shall be applied.

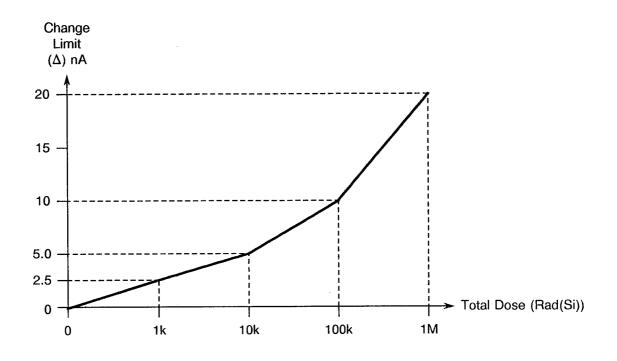


# TABLE 7 - ELECTRICAL MEASUREMENTS DURING AND ON COMPLETION OF IRRADIATION TESTING

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS (Δ)	UNIT
2	Reverse Current 2	I <sub>R2</sub>	As per Table 2	As per Table 2	Note 1	nA

#### **NOTES**

1. The graph given below shall be used to determine the maximum permitted change.





ISSUE 1

# APPENDIX 'A'

Page 1 of 1

# AGREED DEVIATIONS FOR M/A-Com LTD. (G.B.)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
Para. 4.2.2	Para. 9.4, "High Temperature Stabilisation Bake": May be performed at +125(+0-3) °C.